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November 2014

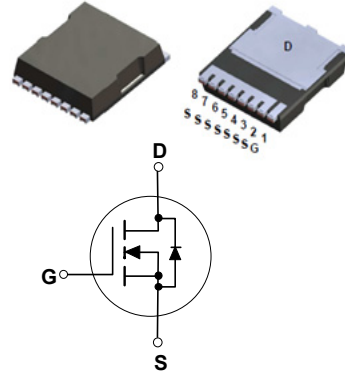
# FDBL0090N40 N-Channel PowerTrench<sup>®</sup> MOSFET 40 V, 240 A, 0.9 mΩ

## Features

- Typical  $R_{DS(on)}$  = 0.65 mΩ at  $V_{GS} = 10V$ ,  $I_D = 80 A$
- Typical  $Q_{g(tot)}$  = 144 nC at  $V_{GS} = 10V$ ,  $I_D = 80 A$
- UIS Capability
- RoHS Compliant

## Applications

- Industrial Motor Drive
- Industrial Power Supply
- Industrial Automation
- Battery Operated tools
- Battery Protection
- Solar Inverters
- UPS and Energy Inverters
- Energy Storage
- Load Switch



For current package drawing, please refer to the Fairchild website at [https://www.fairchildsemi.com/evaluate/package-specifications/packageDetails.html?id=PN\\_PSOFA-008](https://www.fairchildsemi.com/evaluate/package-specifications/packageDetails.html?id=PN_PSOFA-008)

## MOSFET Maximum Ratings $T_J = 25^\circ C$ unless otherwise noted.

| Symbol          | Parameter  | Ratings            | Units         |
|-----------------|--|--------------------|---------------|
| $V_{DSS}$       | Drain-to-Source Voltage                                  | 40                 | V             |
| $V_{GS}$        | Gate-to-Source Voltage                                   | ±20                | V             |
| $I_D$           | Drain Current - Continuous ( $V_{GS}=10$ ) (Note 1)      | $T_C = 25^\circ C$ | 240           |
|                 | Pulsed Drain Current                                     | $T_C = 25^\circ C$ | See Figure 4  |
| $E_{AS}$        | Single Pulse Avalanche Energy (Note 2)                   | 737                | mJ            |
| $P_D$           | Power Dissipation  | 357                | W             |
|                 | Derate Above $25^\circ C$                                | 2.38               | W/ $^\circ C$ |
| $T_J, T_{STG}$  | Operating and Storage Temperature                        | -55 to + 175       | $^\circ C$    |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case                     | 0.42               | $^\circ C/W$  |
| $R_{\theta JA}$ | Maximum Thermal Resistance, Junction to Ambient (Note 3) | 43                 | $^\circ C/W$  |

### Notes:

- 1: Current is limited by bondwire configuration.
- 2: Starting  $T_J = 25^\circ C$ ,  $L = 0.36mH$ ,  $I_{AS} = 64A$ ,  $V_{DD} = 40V$  during inductor charging and  $V_{DD} = 0V$  during time in avalanche.
- 3:  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design, while  $R_{\theta JA}$  is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

## Package Marking and Ordering Information

| Device Marking | Device      | Package |   |   |   |
|----------------|-------------|---------|---|---|---|
| FDBL0090N40    | FDBL0090N40 | MO-299A | - | - | - |

FDBL0090N40 N-Channel PowerTrench<sup>®</sup> MOSFET

**Electrical Characteristics**  $T_J = 25^\circ\text{C}$  unless otherwise noted.

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Units |
|--------|-----------|-----------------|------|------|------|-------|
|--------|-----------|-----------------|------|------|------|-------|

**Off Characteristics**

|              |                                   |   |    |   |           |               |
|--------------|-----------------------------------|---|----|---|-----------|---------------|
| $B_{V_{DS}}$ | Drain-to-Source Breakdown Voltage | $I_D = 250\mu\text{A}$ , $V_{GS} = 0\text{V}$             | 40 | - | -         | V             |
| $I_{DSS}$    | Drain-to-Source Leakage Current   | $V_{DS} = 40\text{V}$ , $T_J = 25^\circ\text{C}$          | -  | - | 1         | $\mu\text{A}$ |
|              |                                   | $V_{GS} = 0\text{V}$ , $T_J = 175^\circ\text{C}$ (Note 4) | -  | - | 1         | mA            |
| $I_{GSS}$    | Gate-to-Source Leakage Current    | $V_{GS} = \pm 20\text{V}$                                 | -  | - | $\pm 100$ | nA            |

**On Characteristics**

|              |                                  |  |     |      |      |            |
|--------------|----------------------------------|--|-----|------|------|------------|
| $V_{GS(th)}$ | Gate to Source Threshold Voltage | $V_{GS} = V_{DS}$ , $I_D = 250\mu\text{A}$                 | 2.0 | 3.3  | 4.0  | V          |
| $R_{DS(on)}$ | Drain to Source On Resistance    | $I_D = 80\text{A}$ , $T_J = 25^\circ\text{C}$              | -   | 0.65 | 0.90 | m $\Omega$ |
|              |                                  | $V_{GS} = 10\text{V}$ , $T_J = 175^\circ\text{C}$ (Note 4) | -   | 1.10 | 1.50 | m $\Omega$ |

**Dynamic Characteristics**

|              |                               |   |   |       |     |          |
|--------------|-------------------------------|---|---|-------|-----|----------|
| $C_{iss}$    | Input Capacitance             | $V_{DS} = 25\text{V}$ , $V_{GS} = 0\text{V}$ ,<br>$f = 1\text{MHz}$ | - | 12000 | -   | pF       |
| $C_{oss}$    | Output Capacitance            |   | - | 3260  | -   | pF       |
| $C_{rss}$    | Reverse Transfer Capacitance  |   | - | 442   | -   | pF       |
| $R_g$        | Gate Resistance               | $f = 1\text{MHz}$   | - | 3.3   | -   | $\Omega$ |
| $Q_{g(ToT)}$ | Total Gate Charge at 10V      | $V_{GS} = 0$ to 10V   | - | 144   | 188 | nC       |
| $Q_{g(th)}$  | Threshold Gate Charge         | $V_{GS} = 0$ to 2V  |   |       |     |          |
| $Q_{gs}$     | Gate-to-Source Gate Charge    | $V_{DD} = 32\text{V}$<br>$I_D = 80\text{A}$                         | - | 66    | -   | nC       |
| $Q_{gd}$     | Gate-to-Drain "Miller" Charge |   | - | 16    | -   | nC       |

**Switching Characteristics**

|              |                |   |   |    |     |    |
|--------------|----------------|---|---|----|-----|----|
| $t_{on}$     | Turn-On Time   | $V_{DD} = 20\text{V}$ , $I_D = 80\text{A}$ ,<br>$V_{GS} = 10\text{V}$ , $R_{GEN} = 6\Omega$ | - | -  | 162 | ns |
| $t_{d(on)}$  | Turn-On Delay  |   | - | 42 | -   | ns |
| $t_r$        | Rise Time      |   | - | 73 | -   | ns |
| $t_{d(off)}$ | Turn-Off Delay |   | - | 83 | -   | ns |
| $t_f$        | Fall Time      |   | - | 50 | -   | ns |
| $t_{off}$    | Turn-Off Time  |   | - | -  | 279 | ns |

**Drain-Source Diode Characteristics**

|          |                               |   |   |     |      |    |
|----------|-------------------------------|---|---|-----|------|----|
| $V_{SD}$ | Source-to-Drain Diode Voltage | $I_{SD} = 80\text{A}$ , $V_{GS} = 0\text{V}$                  | - | -   | 1.25 | V  |
|          |                               | $I_{SD} = 40\text{A}$ , $V_{GS} = 0\text{V}$                  | - | -   | 1.2  | V  |
| $t_{rr}$ | Reverse-Recovery Time         | $I_F = 80\text{A}$ , $dI_{SD}/dt = 100\text{A}/\mu\text{s}$ , | - | 111 | 129  | ns |
| $Q_{rr}$ | Reverse-Recovery Charge       | $V_{DD} = 32\text{V}$   | - | 178 | 214  | nC |

**Note:**

4: The maximum value is specified by design at  $T_J = 175^\circ\text{C}$ . Product is not tested to this condition in production.

## Typical Characteristics

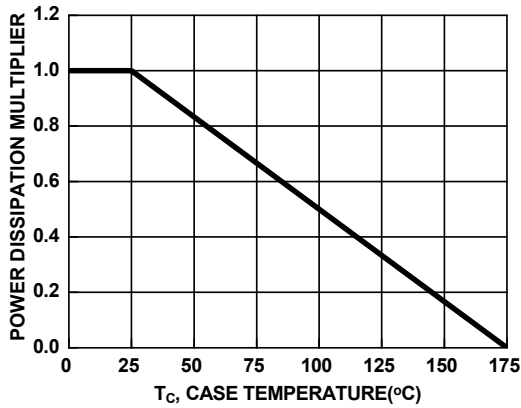


Figure 1. Normalized Power Dissipation vs. Case Temperature

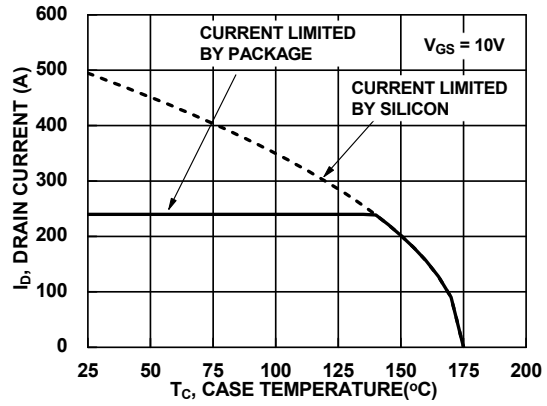


Figure 2. Maximum Continuous Drain Current vs. Case Temperature

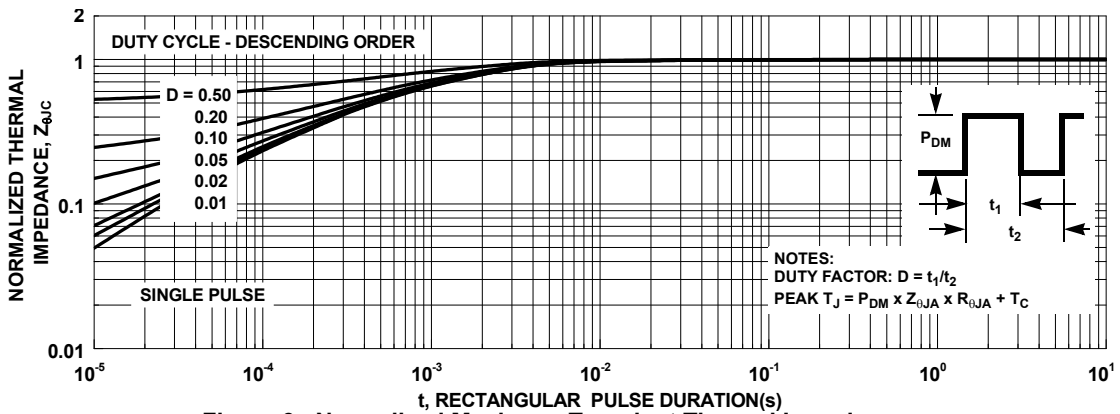


Figure 3. Normalized Maximum Transient Thermal Impedance

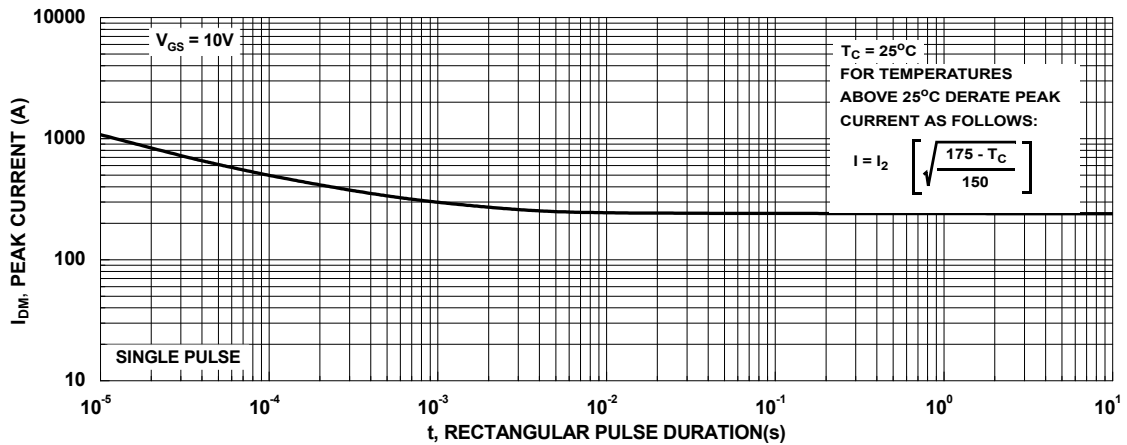


Figure 4. Peak Current Capability

### Typical Characteristics

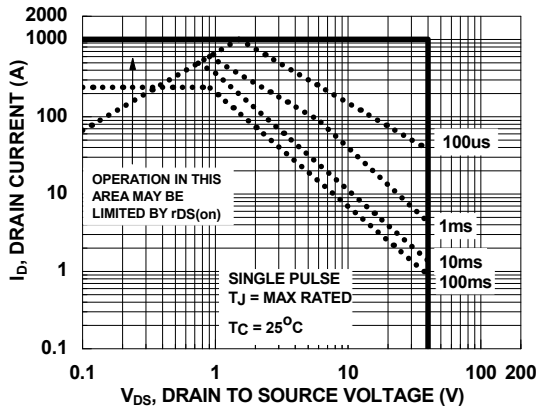
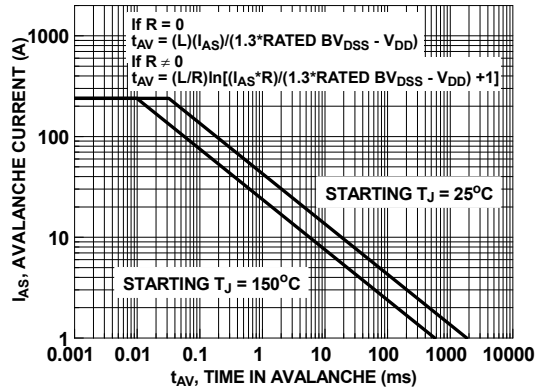


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515  
 Figure 6. Unclamped Inductive Switching Capability

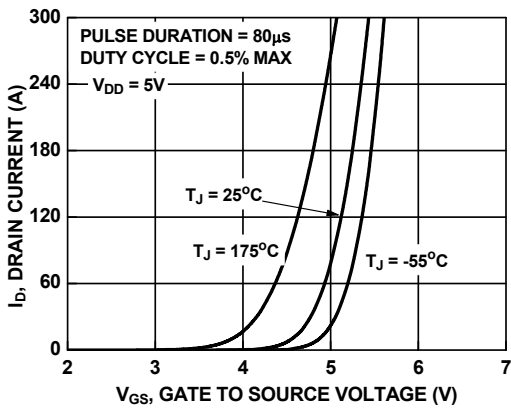


Figure 7. Transfer Characteristics

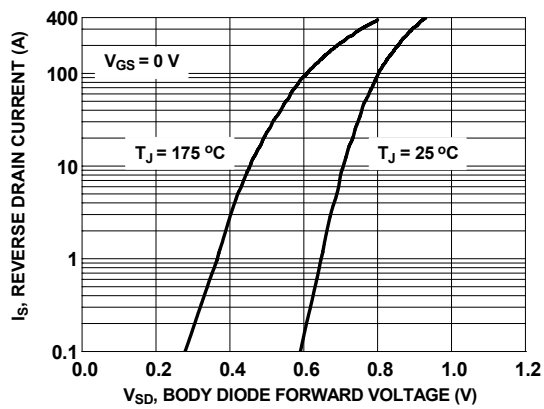


Figure 8. Forward Diode Characteristics

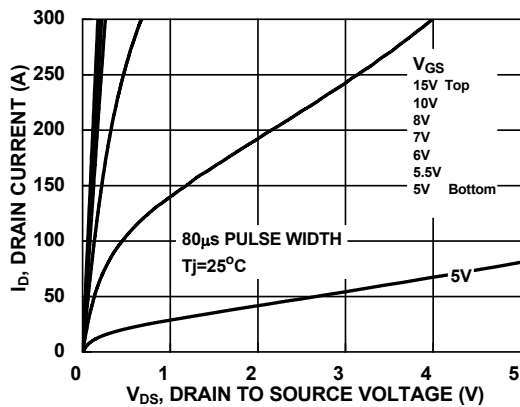


Figure 9. Saturation Characteristics

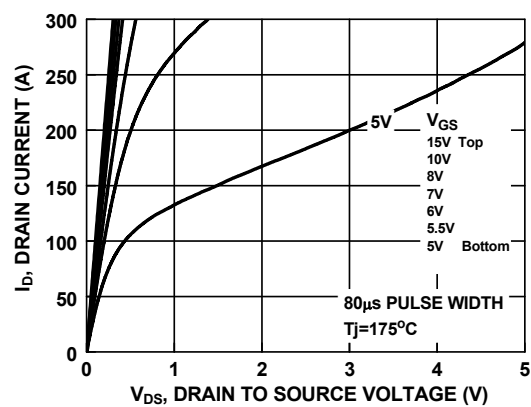


Figure 10. Saturation Characteristics

## Typical Characteristics

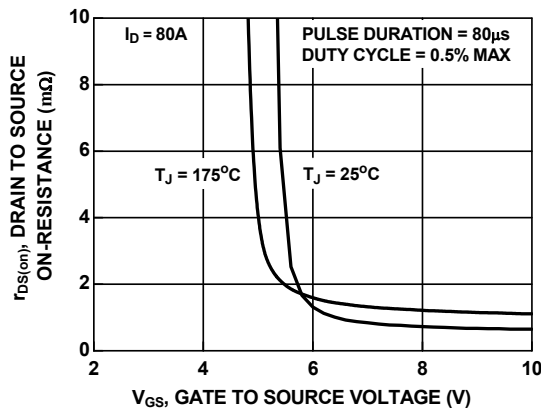


Figure 11.  $R_{DS(on)}$  vs. Gate Voltage

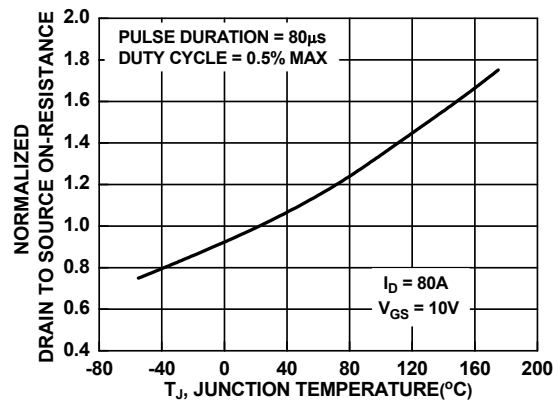


Figure 12. Normalized  $R_{DS(on)}$  vs. Junction Temperature

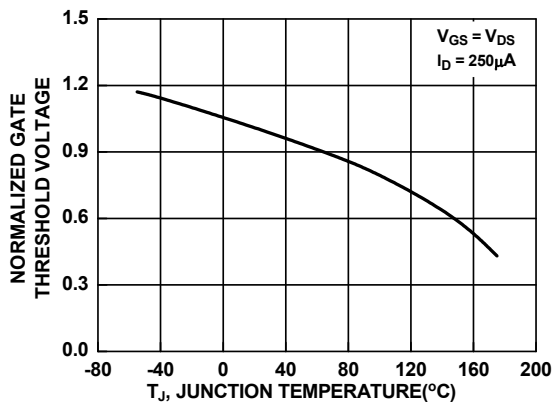


Figure 13. Normalized Gate Threshold Voltage vs. Temperature

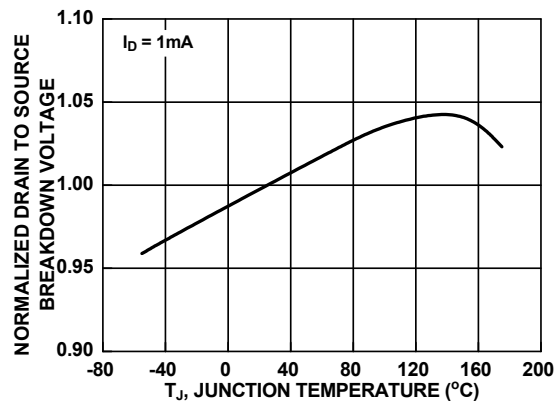


Figure 14. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature

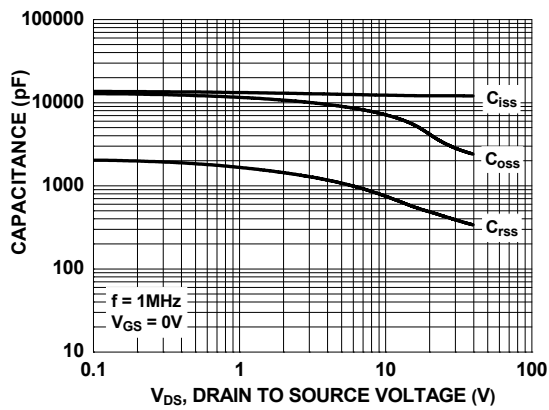


Figure 15. Capacitance vs. Drain to Source Voltage

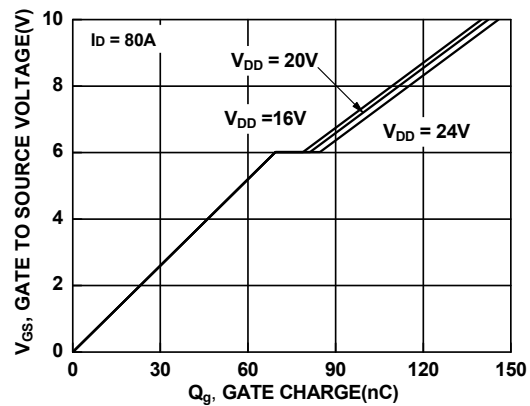






Figure 16. Gate Charge vs. Gate to Source Voltage



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